

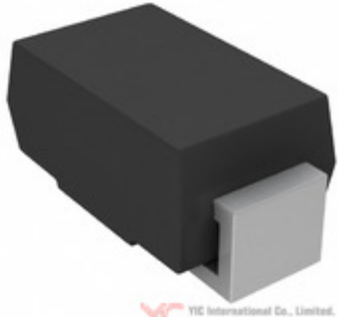
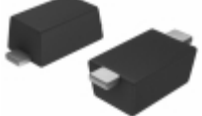
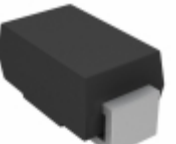
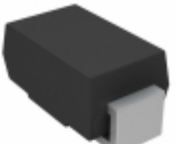

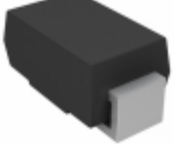
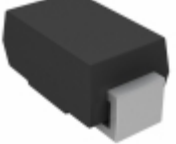

	<p><b>US1GHE3/5AT</b></p>
	<p><b>Hersteller-Teilenummer:</b> US1GHE3/5AT</p> <p><b>Hersteller / Marke:</b> Vishay / Semiconductor - Diodes Division</p> <p><b>Teil der Beschreibung:</b> DIODE GEN PURP 400V 1A DO214AC</p> <p><b>Datenblätter:</b>  <a href="#">1.US1GHE3/5AT.pdf</a>  <a href="#">2.US1GHE3/5AT.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 99000 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	US1GHE3/5AT
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 400V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	99000 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1V @ 1A
Strom - Sperrleckstrom @ Vr	10µA @ 400V
Spannung - Sperr (Vr) (max)	400V
Geschwindigkeit	Fast Recovery = 200mA (Io)
Rückwärts-Erholzeit (Trr)	50ns
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	15pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)



















































US1GHE3/5AT ist neu im Original, Suche US1GHE3/5AT Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie US1GHE3/5AT Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage US1GHE3/5AT: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>US1GFA</b> Fairchild/ON Semiconductor DIODE GEN PURP 400V 1A SOD123FA</p>	 <p><b>US1GHE3/5AT</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 1A DO214AC</p>	 <p><b>US1GHE3_A/H</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 1A DO214AC</p>	 <p><b>US1GHE3</b> VISHAY</p>
 <p><b>US1GHE3/61T</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 400V 1A DO214AC</p>	 <p><b>US1GHE3_A/H</b> Vishay / Semiconductor - Diodes Division DIODE GEN PURP 200V 1A DO214AC</p>	 <p><b>US1GHE3/61T</b> Electro-Films (EFI) / Vishay DIODE GEN PURP 400V 1A DO214AC</p>	 <p><b>US1GFA</b> AMI Semiconductor / ON Semiconductor DIODE GEN PURP 400V 1A SOD123FA</p>

heiße Teile

Mehr

 US1B-E3/5AT	 US1B-E3/5AT	 US1B-E3/61T	 US1B-E3/61T	 US1B-M3/61T
 US1B-M3/61T	 US1BHE3/5AT	 US1BHE3/5AT	 US1BHE3/61T	 US1BHE3/61T
 US1C-E3/61T	 US1D-13-F	 US1D-E3/61T	 US1D-E3/61T	 US1D-M3/61T
 US1D-M3/61T	 US1DWF-7	 US1DWF-7	 US1G-13-F	 US1G-E3/61T
 US1G-E3/61T	 US1G-M3/61T	 US1G-M3/61T	 US1G/11T	 US1GHE3/5AT
 US1GHE3/61	 US1GHE3/61T	 US1GHE3/61T	 US1GHE3_A/H	 US1GHE3_A/H
 US1GWF-7	 US1GWF-7	 US1J-13-F	 US1J-5AT	 US1J-E3/5AT
 US1J-E3/5AT	 US1J-E3/61T	 US1J-E3/61T	 US1J-M3/61T	 US1J-M3/61T
 US1J/11T	 US1J/61T	 US1JE-TP	 US1K-13-F	 US1K-E3/61T
 US1K-E3/61T	 US1K-E3D/H	 US1K-M3/5AT	 US1K-M3/5AT	 US1K-M3/61T

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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